

ICNS-13 2019 Quick Reference Guide

Rooms	Sunday	Monday	Tuesday	Wednesday	Thursday	Friday		
Evergreen Foyer Lobby Level	Registration 6:30 pm - 8:30 pm	Registration 8:00 am - 8:30 pm	Registration 8:00 am - 8:30 pm	Registration 8:00 am - 8:30 pm	Registration 8:00 am - 12:00 pm	Registration 8:00 am - 12:00 pm		
Grand Ballroom Second Floor	Exhibit 6:30 pm - 8:30 pm Welcome Reception 6:30 pm - 8:30 pm	Exhibit 10:00 am - 12:30 pm 2:00 pm - 5:00 pm 6:30 pm - 8:30 pm Poster Set-Up 1:00 pm - 6:00 pm Poster Session 6:30 pm - 8:30 pm	Exhibit 10:00 am - 12:30 pm 2:00 pm - 5:00 pm 6:30 pm - 8:30 pm Poster Set-Up 1:00 pm - 6:00 pm Poster Session 6:30 pm - 8:30 pm	Exhibit 10:00 am - 12:30 pm 2:00 pm - 5:00 pm				
Evergreen Ballroom E-I Lobby Level	Opening Ceremony Plenary Session 8:45 am - 12:15 pm						Plenary Session Closing Ceremony 8:30 am - 12:30 pm	
Evergreen Ballroom A-C Lobby Level	(G) Epitaxial Growth 2:00 pm - 6:00 pm		(G) Epitaxial Growth 8:30 am - 12:30 pm 2:00 pm - 6:00 pm	(H) Nanostructures and Nano-Devices 8:30 am - 10:15 am (G) Epitaxial Growth 10:15 am - 12:30 pm 2:00 pm - 6:00 pm			(G) Epitaxial Growth 8:00 am - 11:30 am	
Evergreen Ballroom E-F Lobby Level	(A) Light Emitting Devices 2:00 pm - 6:00 pm	(A) Light Emitting Devices 8:30 am - 12:30 pm 2:00 pm - 6:00 pm	(A) Light Emitting Devices 8:30 am - 12:30 pm 2:00 pm - 6:00 pm	(A) Light Emitting Devices 8:30 am - 12:30 pm 2:00 pm - 6:00 pm			(A) Light Emitting Devices 8:00 am - 9:30 am (B) Electron Transport Devices 10:00 am - 11:30 am	
Cedar Ballroom Second Floor	(B) Electron Transport Devices 2:00 pm - 6:00 pm	(B) Electron Transport Devices 8:30 am - 12:30 pm 2:00 pm - 6:00 pm	(B) Electron Transport Devices 8:30 am - 12:30 pm 2:00 pm - 6:00 pm	(B) Electron Transport Devices 8:30 am - 10:15 am 2:00 pm - 6:00 pm (E) Processing, Fabrication and Thermal Management 10:45 am - 12:30 pm Rump Session I 6:30 pm - 8:30 pm			(C) Photovoltaics, Energy Harvesting and Photo Detectors 8:00 am - 11:30 am	
Regency Ballroom A-C Second Floor	(I) Optical and Electronic Properties 2:00 pm - 3:45 pm (F) Bulk Growth 4:15 pm - 6:00 pm	(I) Optical and Electronic Properties 8:30 am - 12:30 pm 2:00 pm - 3:45 pm (F) Bulk Growth 4:15 pm - 6:00 pm	(I) Optical and Electronic Properties 8:30 am - 12:30 pm 2:00 pm - 3:45 pm (F) Bulk Growth 4:15 pm - 6:00 pm	(M) New Materials and Device Concepts 8:30 am - 12:30 pm (F) Bulk Growth 2:00 pm - 3:45 pm (A) Light Emitting Devices 4:15 pm - 6:00 pm Rump Session II 6:30 pm - 8:30 pm			(I) Optical and Electronic Properties 8:00 am - 9:30 am (J) Defect Characterization and Engineering 10:00 am - 11:30 am	
Regency Ballroom E-G Second Floor	(H) Nanostructures and Nano-Devices 2:00 pm - 3:45 pm (D) Sensors, Actuators and Acoustic Devices 4:15 pm - 6:00 pm	(H) Nanostructures and Nano-Devices 8:30 am - 10:15 am 2:00 pm - 3:45 pm (M) New Materials and Device Concepts 10:45 am - 12:30 pm (L) Theory and Simulation 4:15 pm - 6:00 pm	(H) Nanostructures and Nano-Devices 8:30 am - 10:15 am 2:00 pm - 3:45 pm (M) New Materials and Device Concepts 10:45 am - 12:30 pm (L) Theory and Simulation 4:15 pm - 6:00 pm	(J) Defect Characterization and Engineering 8:30 am - 10:15 am 2:00 pm - 3:45 pm (H) Nanostructures and Nano-Devices 10:45 am - 12:30 pm (K) Structural Analysis 4:15 pm - 6:00 pm Rump Session III 6:30 pm - 8:30 pm			(D) Sensors, Actuators and Acoustic Devices 8:00 am - 9:30 am (E) Processing, Fabrication and Thermal Management 10:00 am - 11:30 am	
Siteseeing Cruise & Boeing Tour							Optional Tours / Excursions 11:30 am - 5:00 pm	
Chihuly Garden & Glass							Conference Reception 6:00 pm - 9:00 pm	